



BCP68

NPN SILICON TRANSISTOR

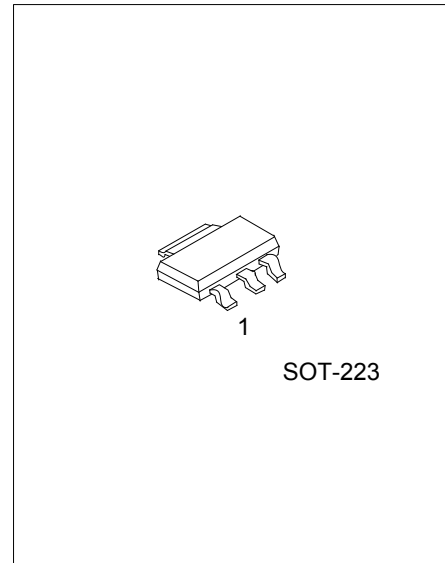
NPN MEDIUM POWER TRANSISTOR

FEATURES

- * High current (max. 1A)
- * Low voltage (max. 20V).
- * Complementary to UTC BCP69

APPLICATIONS

- * General purpose switching and amplification under high current conditions.



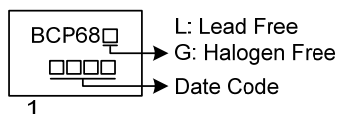
ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
BCP68L-xx-AA3-R	BCP68G-xx-AA3-R	SOT-223	B	C	E	Tape Reel

Note: Pin Assignment: B: Base C: Collector E: Emitter

<p>BCP68G-xx-AA3-R</p> <p>(1) Packing Type (2) Package Type (3) Rank (4) Green Package</p>	<p>(1) R: Tape Reel (2) AA3: SOT-223 (3) xx: refer to Classification of h_{FE3} (4) G: Halogen Free and Lead Free, L: Lead Free</p>
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MARKING



■ ABSOLUTE MAXIMUM RATINGS ($T_A=25^\circ\text{C}$, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Collector-Base Voltage (Open Emitter)	V_{CBO}	32	V
Collector-Emitter Voltage (Open Base)	V_{CEO}	20	V
Emitter-Base Voltage (Open Collector)	V_{EBO}	5	V
Collector Current	DC	I_C	1
	Peak	I_{CM}	2
Peak Base Current	I_{BM}	200	mA
Total Power Dissipation ($T_A \leq 25^\circ\text{C}$)	P_D	1.35	W
Junction Temperature	T_J	+150	$^\circ\text{C}$
Operating Temperature	T_{OPR}	-45 ~ +150	$^\circ\text{C}$
Storage Temperature	T_{STG}	-65 ~ +150	$^\circ\text{C}$

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Junction To Ambient	θ_{JA}	91	$^\circ\text{C/W}$

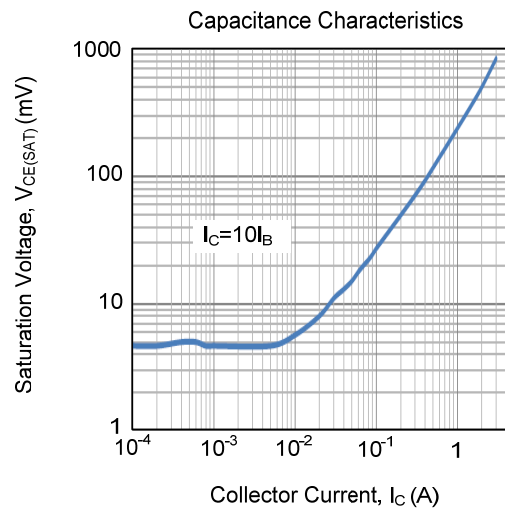
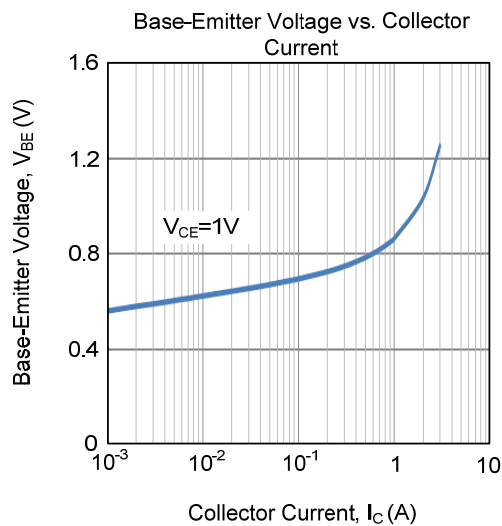
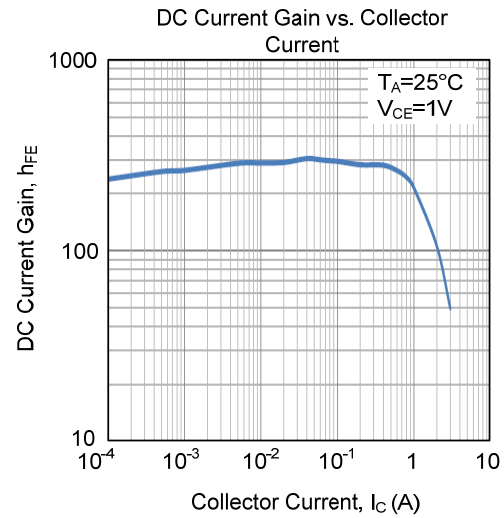
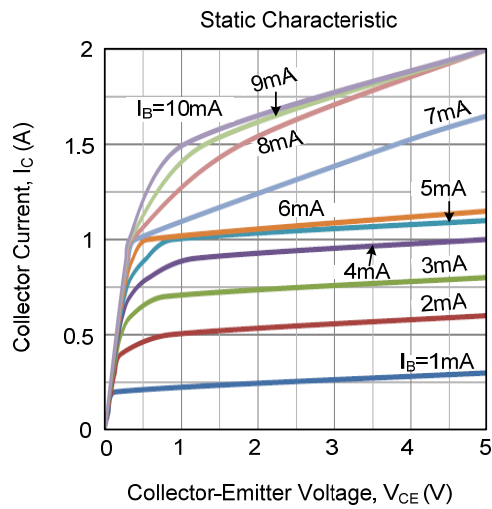
■ ELECTRICAL CHARACTERISTICS ($T_J = 25^\circ\text{C}$, unless otherwise specified.)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	$I_C=1\text{A}, I_B=100\text{mA}$			500	mV
Base-Emitter Voltage	V_{BE}	$I_C=5\text{mA}, V_{CE}=10\text{V}$		620		mV
		$I_C=1\text{A}, V_{CE}=1\text{V}$			1	V
Collector Cut-off Current	I_{CBO}	$I_E=0, V_{CB}=25\text{V}$			100	nA
		$I_E=0, V_{CB}=25\text{V}, T_J=150^\circ\text{C}$			10	μA
Emitter Cut-off Current	I_{EBO}	$I_C=0, V_{EB}=5\text{V}$			100	nA
DC Current Gain	h_{FE}	$I_C=500\text{mA}, V_{CE}=1\text{V}$	85		375	
	h_{FE1}	$I_C=5\text{mA}, V_{CE}=10\text{V}$	50			
	h_{FE2}	$I_C=1\text{A}, V_{CE}=1\text{V}$	60			
	h_{FE3}	$I_C=500\text{mA}, V_{CE}=1\text{V}$	100		250	
Collector Capacitance	C_C	$I_E=i_e=0, V_{CB}=5\text{V}, f=1\text{MHz}$		48		pF
Transition Frequency	f_T	$I_C=-10\text{mA}, V_{CE}=-5\text{V}, f=100\text{MHz}$	40			MHz
DC Current Gain Ratio of the Complementary Pairs	$\frac{h_{FE1}}{h_{FE2}}$	$ I_C =0.5\text{A}, V_{CE} =1\text{V}$			1.6	

■ CLASSIFICATION OF h_{FE3}

RANK	16	25
RANGE	100~250	160~375

TYPICAL CHARACTERISTICS



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